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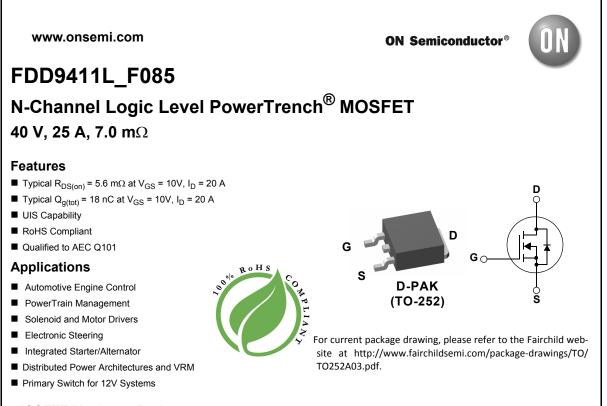


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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MOSFET Maximum Ratings T₁ = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		40	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	25	•	
D	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	22	mJ	
P _D	Power Dissipation		48.4	W	
	Derate Above 25°C		0.32	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		3.1	°C/W	
R _{0JA}	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	52	°C/W	

Notes:

1: Current is limited by bondwire configuration.

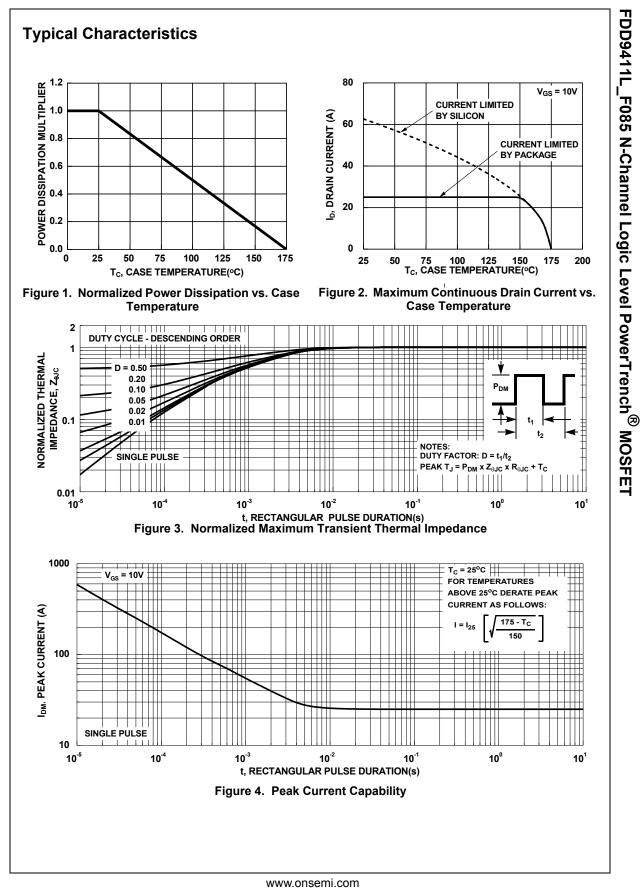
2: Starting T_J = 25°C, L = 0.1mH, I_{AS} = 21A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{0,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder $R_{\theta,JA}$ is guaranteed by design, while $R_{\theta,JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

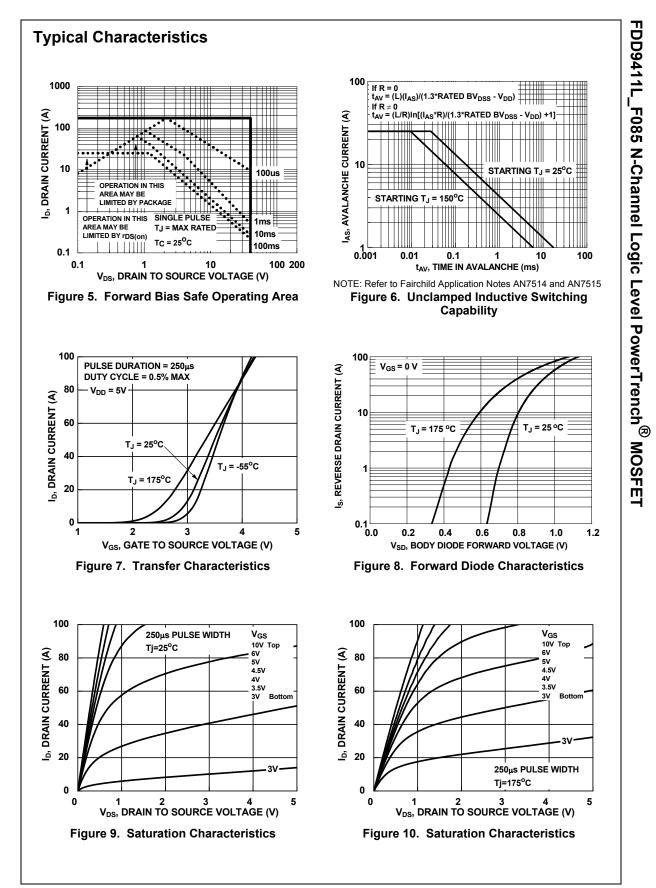
Package Marking and Ordering Information

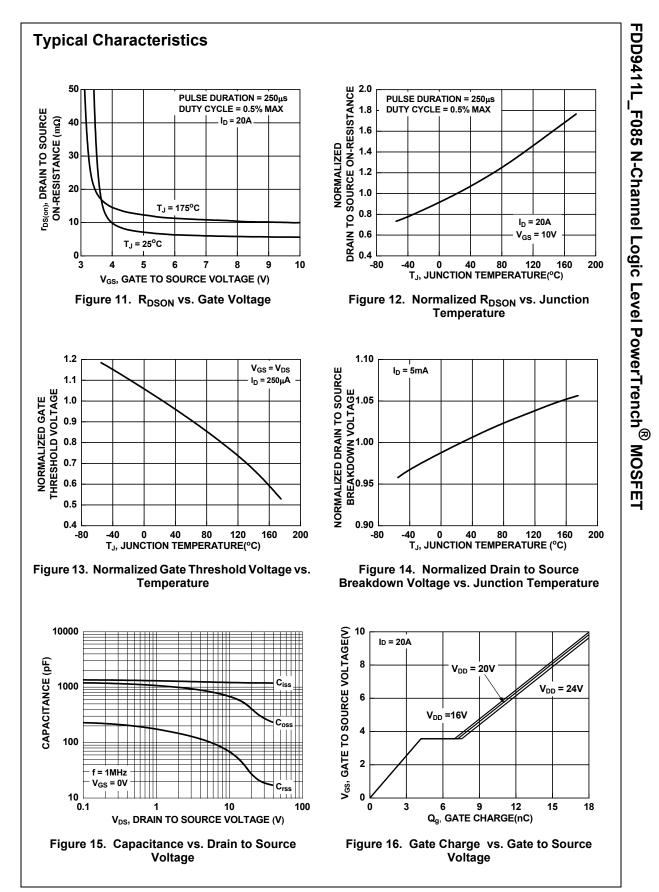
	Device Marking	Device	Package	Reel Size	Tape Width	Quantity
ĺ	FDD9411L	FDD9411L_F085	D-PAK(TO-252)	13"	16mm	2500units

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA,	V _{GS} = 0V	40	-	-	V
		V _{DS} =40V,		-	-	1	μA
I _{DSS}	Drain-to-Source Leakage Current		$T_{\rm J} = 175^{\rm o}C$ (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V_{GS} = ±20V		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		1.0	1.8	3.0	V
00(11)		$I_D = 20A, V_{GS} = 4.5V$		-	7.9	11.5	mΩ
R _{DS(on)}	Drain to Source On Resistance			-	5.6	7.0	mΩ
20(01.)		V _{GS} = 10V	$T_J = 25^{\circ}C$ $T_J = 175^{\circ}C$ (Note 4)	-	9.8	12.4	mΩ
C _{iss}	Input Capacitance	V _{DS} = 20V, V _{GS} = 0V, f = 1MHz			1210	-	pF
C _{oss}	Output Capacitance			-	413	-	pF
C _{rss}	Reverse Transfer Capacitance			-	28	-	pF
R _g	Gate Resistance	f = 1MHz		-	2.6	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V \qquad V_{DD} = 32V \\ V_{GS} = 0 \text{ to } 2V \qquad I_D = 20A$		-	18	27	nC
Q _{g(th)}	Threshold Gate Charge			-	2	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	4	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	3	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	17	ns
t _{d(on)}	Turn-On Delay			-	7	-	ns
t _r	Rise Time	V_{DD} = 20V, I _D = 20A, V _{GS} = 10V, R _{GEN} = 6Ω		-	4	-	ns
t _{d(off)}	Turn-Off Delay			-	20	-	ns
t _f	Fall Time			-	4	-	ns
t _{off}	Turn-Off Time			-	-	36	ns
Drain-S	ource Diode Characteristics						
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} =20A, V _{GS} = 0V		-	-	1.25	V
		I _{SD} = 10A, V _{GS} = 0V		-	-	1.2	V
t _{rr}	Reverse-Recovery Time	$I_F = 20A, dI_{SD}/dt = 100A/\mu s$		-	36	54	ns
Q _{rr}	Reverse-Recovery Charge	$v_{DD} = 32v$		-	23	34	nC
Q _{rr} Note:	Reverse-Recovery Charge kimum value is specified by design at $T_J = 175$	V _{DD} = 32V		-	23	34	n

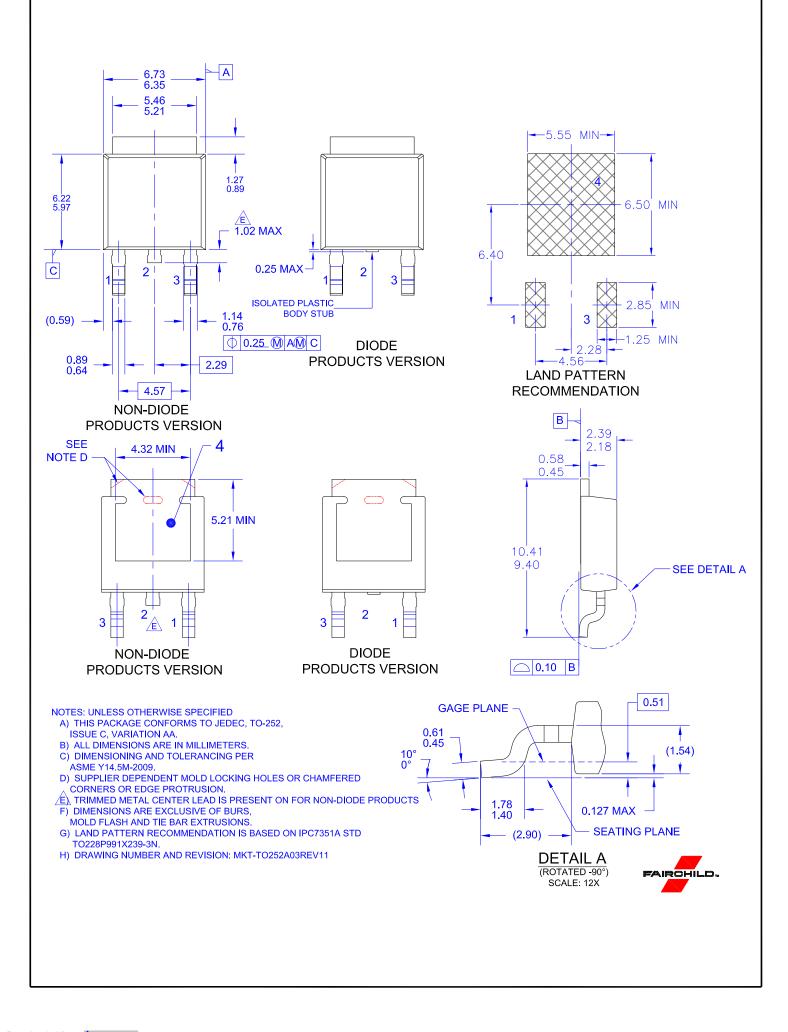
FDD9411L_F085 N-Channel Logic Level PowerTrench[®] MOSFET







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